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IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant:

Hattangady et al.

Art Unit:

2815

Serial No.:

10/783,081

Examiner:

Richards, N.

Filing Date:

02/19/2004

Docket No.:

TI-31017.1

Customer No.:

23494

Conf. No.:

6261

Title:

SEMICONDUCTOR WITH A NITRIDED SILICON GATE OXIDE AND

METHOD

CERTIFICATION OF FACSIMILE TRANSMISSION

I hereby certify that the following papers are being transmitted by facsimile to the U.S. Patent and Trademark Office at 703-872-9306 on the date shown below:

Secquesine J. Garner, Reg. No. 36,144

May 24, 2005

Date

FACSIMILE COVER SHEET

X FACSIMILE COVER SHEET NEW APPLICATION DECLARATION (# Pages) ASSIGNMENT (# Pages) FORMAL DRAWINGS INFORMAL DRAWINGS CONTINUATION APP'N (# Pages) DIVISIONAL APP'N		X AMENDMENT (5 Pages) X EOT3mth (2 Pages) NOTICE OF APPEAL (# Pages) APPEAL (# Pages) ISSUE FEE (# Pages) REPLY BRIEF (IN TRIPLICATE) (# Pages)
NAME OF INVENTOR(S): Hattangady		RECEIPT DATE & SERIAL NO.: Serial No.: 10/783,081
Semiconductor with a Nitrided		Filing Date: 2/19/2004 PE A 25
TI FILE NO.: TI-31017.1	DEPOSIT ACCT. NO.: 20-0668	JCWS 2005
FAXED: 5/24/2005 DUE: 2/28/2005 ATTY/SEC'Y: JJG		

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Texas Instruments Incorporated PO Box 655474, M/S 3999 Dallas, TX 75074



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AMENDMENT UNDER 37 CFR 1.111

CERTIFICATION OF FACSIMILE TRANSMISSION

Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450 I hereby certify that the following papers are being transmitted by facsimile to the U.S. Patent and Trademark) Office at (793) 872 - 9306 on 5/24/2005.

Jacqueline J. Garner Reg. No. 36,144

Dear Sir:

The following amendments and remarks are offered in response to the Examiner's Office Action dated 11/30/2004. They are respectfully submitted as a full and complete response to that Action.

Please amend the above-referenced application as follows:

There are no Amendments to the Specification.

Amendments to the Claims are reflected in the listing of claims that begin on page 2 of this paper.

There are no Amendments to the Drawings.

The Remarks begin on page 4.